

# Pengke Li

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/2271767/publications.pdf>

Version: 2024-02-01

23

papers

750

citations

759233

12

h-index

713466

21

g-index

23

all docs

23

docs citations

23

times ranked

955

citing authors

#	ARTICLE	IF	CITATIONS
1	Electrons and holes in phosphorene. <i>Physical Review B</i> , 2014, 90, .	3.2	148
2	Optical Spin Injection and Spin Lifetime in Ge Heterostructures. <i>Physical Review Letters</i> , 2012, 108, 156603.	7.8	89
3	Silicon spin communication. <i>Applied Physics Letters</i> , 2011, 99, 082502.	3.3	81
4	Spin-Orbit Symmetries of Conduction Electrons in Silicon. <i>Physical Review Letters</i> , 2011, 107, 107203.	7.8	79
5	Intrinsic spin lifetime of conduction electrons in germanium. <i>Physical Review B</i> , 2012, 86, .	3.2	64
6	Symmetry, distorted band structure, and spin-orbit coupling of group-III metal-monochalcogenide monolayers. <i>Physical Review B</i> , 2015, 92, .	3.2	51
7	Anisotropy-Driven Spin Relaxation in Germanium. <i>Physical Review Letters</i> , 2013, 111, 257204.	7.8	44
8	Theory of Spin-Dependent Phonon-Assisted Optical Transitions in Silicon. <i>Physical Review Letters</i> , 2010, 105, 037204.	7.8	38
9	Inelastic electron tunneling spectroscopy of local "spin accumulation" devices. <i>Applied Physics Letters</i> , 2014, 104, .	3.3	34
10	Interpreting current-induced spin polarization in topological insulator surface states. <i>Physical Review B</i> , 2016, 93, .	3.2	25
11	Electrons, holes, and spin in the IV-VI monolayer four-six-enes. <i>Physical Review B</i> , 2016, 94, .	3.2	21
12	Spin-dependent optical properties in strained silicon and germanium. <i>Physical Review B</i> , 2013, 87, .	3.2	18
13	Self-consistent model of spin accumulation magnetoresistance in ferromagnet/insulator/semiconductor tunnel junctions. <i>Physical Review B</i> , 2014, 90, .	3.2	11
14	Illuminating "spin-polarized" Bloch wave-function projection from degenerate bands in decomposable centrosymmetric lattices. <i>Physical Review B</i> , 2018, 97, .	3.2	9
15	Spin-Polarization Control in a Two-Dimensional Semiconductor. <i>Physical Review Applied</i> , 2016, 5, .	3.8	8
16	Excitons without effective mass: Biased bilayer graphene. <i>Physical Review B</i> , 2019, 99, .	3.2	8
17	Intrinsic two-dimensional states on the pristine surface of tellurium. <i>Physical Review B</i> , 2018, 97, .	3.2	7
18	Tunable spin junction. <i>Applied Physics Letters</i> , 2009, 94, 192108.	3.3	5

#	ARTICLE	IF	CITATIONS
19	Robust zero-energy bound states in a helical lattice. Physical Review B, 2017, 96, ,.	3.2	5
20	Mid-infrared photoconductivity spectra of single tellurium nanowires. Journal of Applied Physics, 2020, 128, 063105.	2.5	4
21	Origin of the electromagnetic anisotropy in monolayer black phosphorus. Physical Review B, 2019, 100, .	3.2	1
22	Spintronics using Si. , 2011, ,.		0
23	<math>\langle g \rangle</math>-factor anisotropy driven spin relaxation in germanium. Proceedings of SPIE, 2014, ,.	0.8	0